

GaAs InGaP HBT MMIC DRIVER AMPLIFIER, 3.0 - 4.5 GHz

Typical Applications

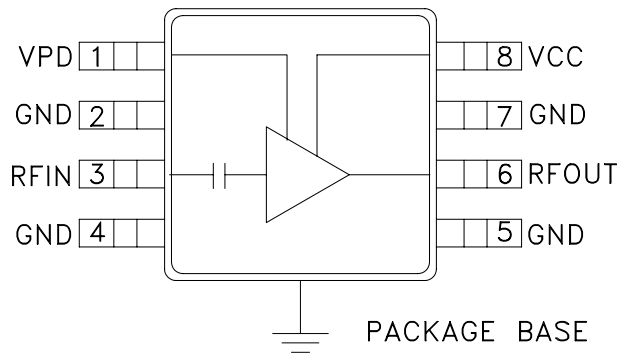
The HMC326MS8G / HMC326MS8GE is ideal for:

- Microwave Radios
- Broadband Radio Systems
- Wireless Local Loop Driver Amplifier

Features

- Psat Output Power: +26 dBm
- > 40% PAE
- Output IP3: +36 dBm
- High Gain: 21 dB
- Vs: +5V
- Ultra Small Package: MSOP8G

Functional Diagram



General Description

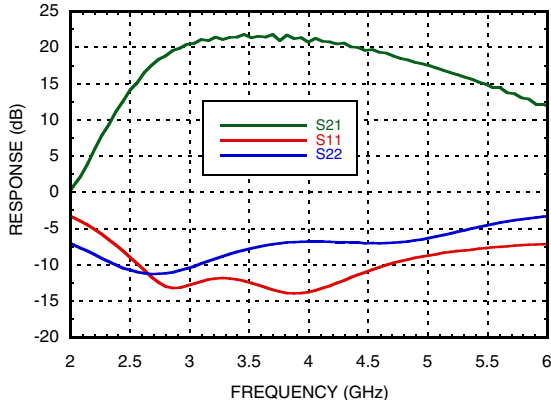
The HMC326MS8G & HMC326MS8GE are high efficiency GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC driver amplifiers which operate between 3.0 and 4.5 GHz. The amplifier is packaged in a low cost, surface mount 8 leaded package with an exposed base for improved RF and thermal performance. The amplifier provides 21 dB of gain and +26 dBm of saturated power from a +5V supply voltage. Power down capability is available to conserve current consumption when the amplifier is not in use. Internal circuit matching was optimized to provide greater than 40% PAE.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_s = 5\text{V}$, $V_{pd} = 5\text{V}$

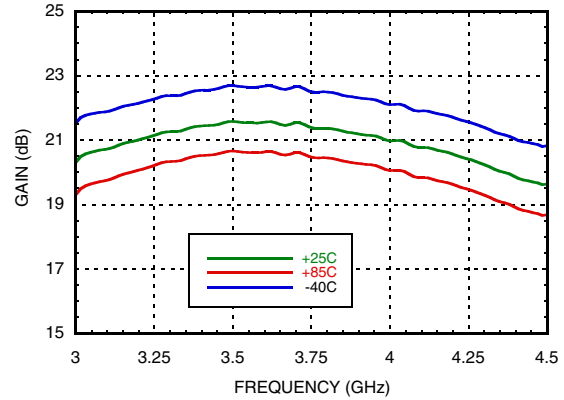
Parameter	Min.	Typ.	Max.	Units	
Frequency Range	3.0 - 4.5			GHz	
Gain	18	21		dB	
Gain Variation Over Temperature		0.025	0.035	dB / °C	
Input Return Loss		12		dB	
Output Return Loss		7		dB	
Output Power for 1dB Compression (P1dB)	21	23.5		dBm	
Saturated Output Power (Psat)		26		dBm	
Output Third Order Intercept (IP3)	32	36		dBm	
Noise Figure		5		dB	
Supply Current (Icc)	Vpd = 0V		1	uA	
Supply Current (Icc)	Vpd = 5V		110	130	160
Control Current (Ipd)		7		mA	
Switching Speed	tOn/tOff		10	ns	

GaAs InGaP HBT MMIC DRIVER AMPLIFIER, 3.0 - 4.5 GHz

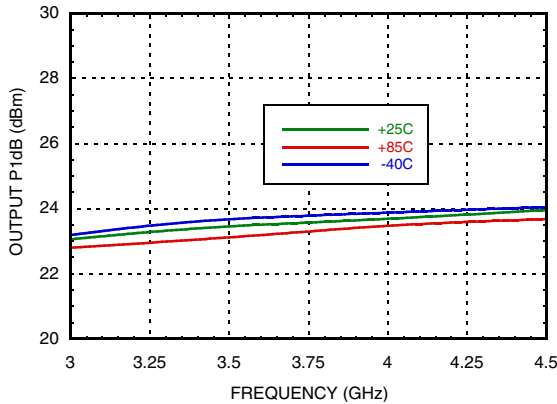
Broadband Gain & Return Loss



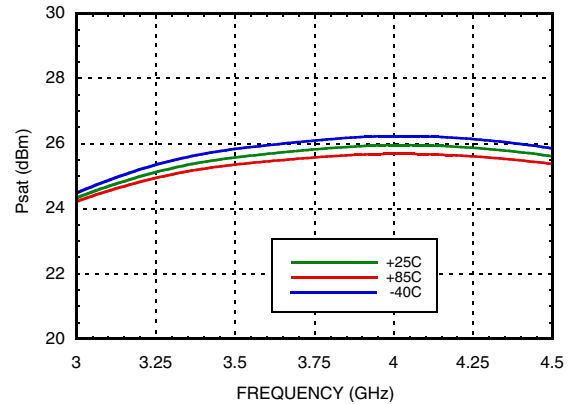
Gain vs. Temperature



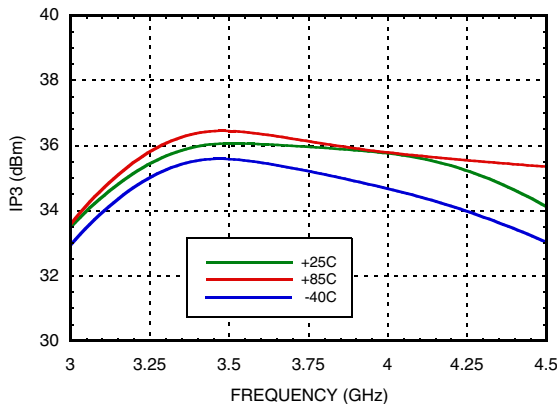
P1dB vs. Temperature



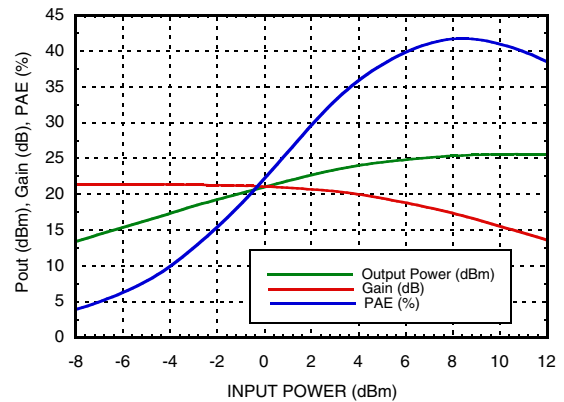
Psat vs. Temperature



Output IP3 vs. Temperature

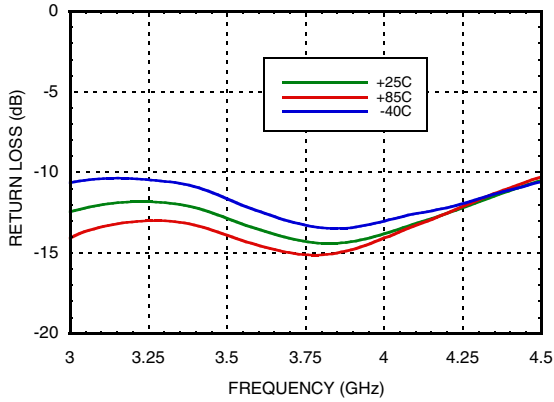


Power Compression @ 3.5 GHz

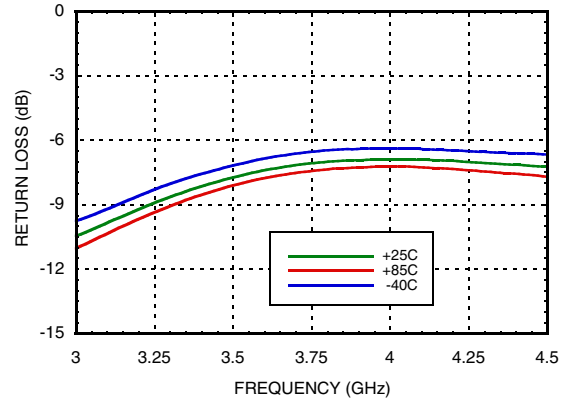


GaAs InGaP HBT MMIC DRIVER AMPLIFIER, 3.0 - 4.5 GHz

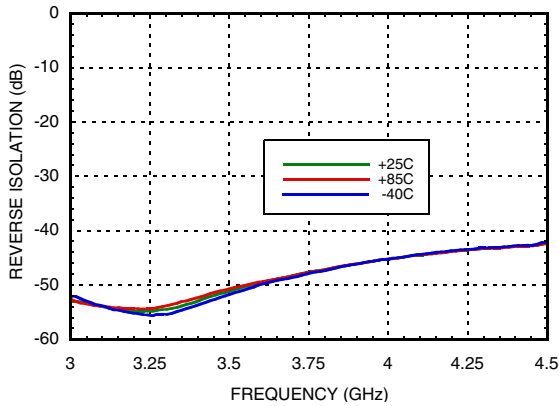
Input Return Loss vs. Temperature



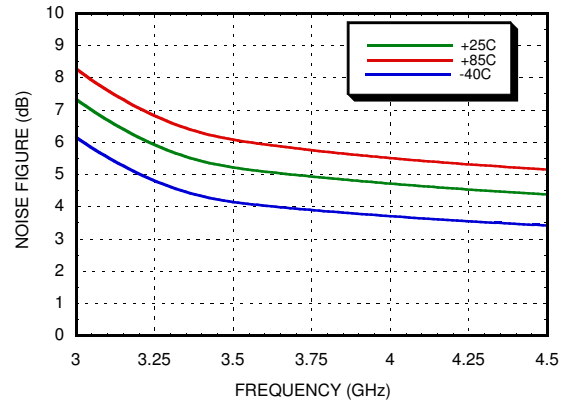
Output Return Loss vs. Temperature



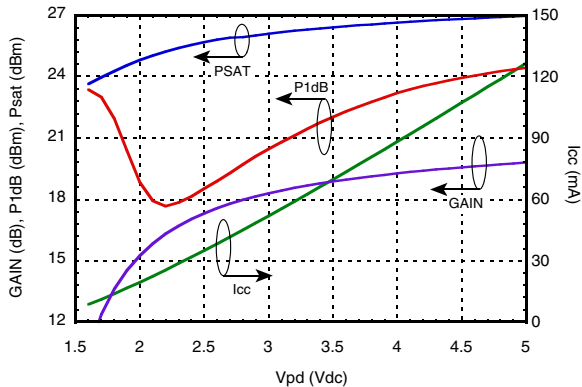
Reverse Isolation vs. Temperature



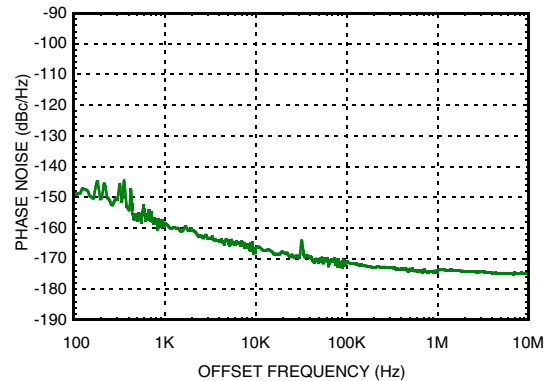
Noise Figure vs. Temperature



Gain, Power & Quiescent Supply Current vs. Vpd @3.5 GHz



Additive Phase Noise Vs Offset Frequency, RF Frequency = 4 GHz, RF Input Power = 10 dBm (Psat)



GaAs InGaP HBT MMIC DRIVER AMPLIFIER, 3.0 - 4.5 GHz

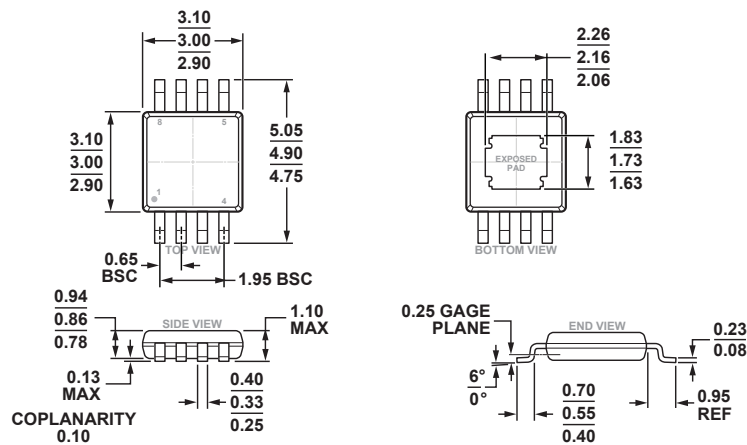
Absolute Maximum Ratings

Collector Bias Voltage (Vcc)	+5.5 Vdc
Control Voltage Range (Vpd)	+5.5 Vdc
RF Input Power (RFIN)(Vs = Vpd = +5Vdc)	+15 dBm
Junction Temperature	150 °C
Continuous P _{diss} (T = 85 °C) (derate 14 mW/°C above 85 °C)	0.916 W
Thermal Resistance (junction to ground paddle)	71 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



COMPLIANT TO JEDEC STANDARDS MO-187-AA-T

8-Lead Mini Small Outline Package with Exposed Pad [MINI_SO_EP]
(RH-8-1)

Dimensions shown in millimeters.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC326MS8G	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H326 XXXX
HMC326MS8GE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H326 XXXX
HMC326MS8GETR	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H326 XXXX
HMC326MS8GTR	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H326 XXXX
104356 - HMC326MS8G	Evaluation Board			

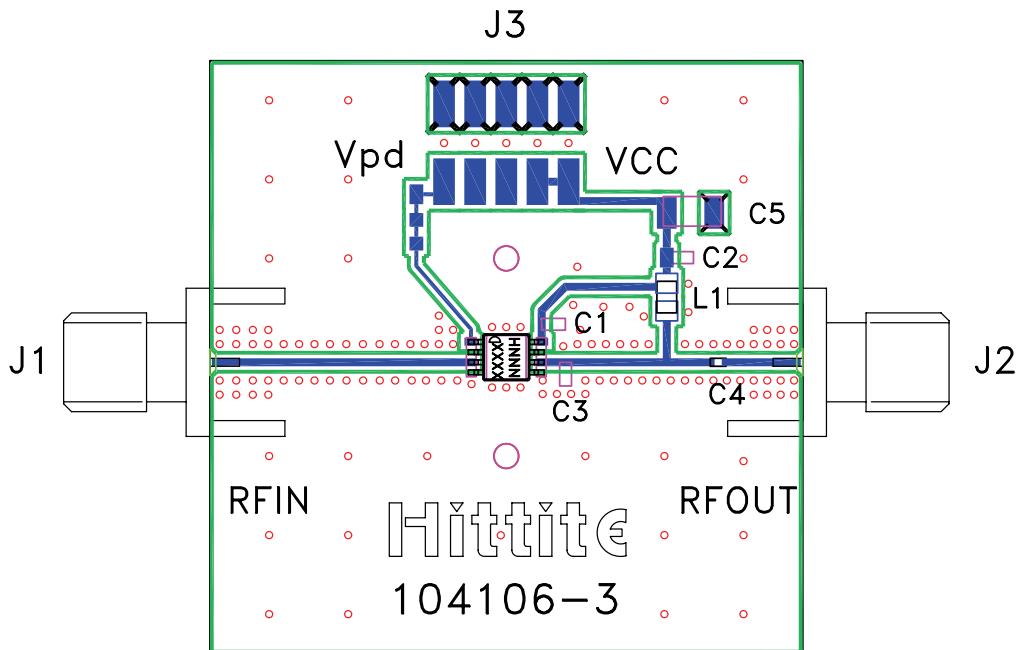
[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

GaAs InGaP HBT MMIC DRIVER AMPLIFIER, 3.0 - 4.5 GHz

Evaluation PCB



List of Materials for Evaluation PCB 104356 [1]

Item	Description
J1 - J2	PCB Mount SMA RF Connector
J3	2mm DC Header
C1 - C2	330 pF Capacitor, 0603 Pkg.
C3	0.7 pF Capacitor, 0603 Pkg.
C4	3.0 pF Capacitor, 0402 Pkg.
C5	2.2 μ F Capacitor, Tantalum
L1	3.3 nH Inductor, 0805 Pkg.
U1	HMC326MS8G / HMC326MS8GE Amplifier
PCB [2]	104106 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350, 10 mil thick, $\tau_r = 3.48$

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Analog Devices upon request.